

CERTIFICATE OF MAILING BY "EXPRESS MAIL"

Express Mail No. EU 013 024 575US

Date of Deposit: August 1, 2003

I hereby certify that this paper or fee is being deposited with the United States Postal Service "Express Mail Post Office to Address" Service under 37 CFR 1.10 on the date indicated above and is addressed to: Mail Stop Patent Application, Commissioner for Patents, PO Box 1450, Alexandria, VA 22313-1450.

August 1, 2003
Date of Signature


Stephen A. Gratton
Attorney for Applicants

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICATION FOR LETTERS PATENT

**SEMICONDUCTOR COMPONENT HAVING CHIP
ON BOARD LEADFRAME
AND METHOD OF FABRICATION**

INVENTORS

**DALSON YE SENG KIM
JEFFREY TOH TUCK FOOK
LEE CHOON KUAN**

Stephen A. Gratton
THE LAW OFFICE OF STEPHEN A. GRATTON
2764 South Braun Way
Lakewood, CO 80228
(303) 989 6353

ATTORNEY'S DOCKET NO. 02-1467

5 Field of the Invention

 This invention relates generally to semiconductor manufacture and packaging. More particularly, this invention relates to a semiconductor component having a chip on board leadframe, to a method for fabricating the component, and to systems incorporating the component.

Background of the Invention

 Semiconductor components, such as packages and BGA devices, are being manufactured with a chip scale outline, and with a higher pin count than conventional plastic or ceramic components. Semiconductor components typically include a substrate, a semiconductor die, and terminal contacts, such as balls, bumps or pins, arranged in an area array, such as a ball grid array (BGA), or a pin grid array (PGA). Semiconductor components can also include an encapsulant which at least partially encapsulates the die and the substrate.

 Different methods are employed in the industry for fabricating semiconductor components. One conventional method uses a rigid substrate, such as a reinforced polymer laminate, attached to the die in a chip on board (COB) or a board on chip (BOC) configuration. The substrate includes conductors, such as copper traces, that are wire bonded to the bond pads on the die. The substrate can also include bonding sites in electrical communication with the conductors for mounting the terminal contacts in the required area array.

 Another method for fabricating semiconductor components uses a metal leadframe that is attached and wire bonded to the die. The metal leadframe includes leadfingers which include bonding sites for wire bonding wire interconnects to the leadframe. The leadfingers are also typically bent or shaped to form the terminal contacts for the components.

5 One advantage of metal leadframes is that they are
inexpensive to manufacture, and can be used with a variety
of conventional packaging equipment, such as wire bonders,
die attachers, conveyors and magazines. However, one
problem with metal lead frames occurs when wire bonded
10 wires short to bus bars physically and electrically
connecting different leadfingers of the lead frames. This
problem is compounded by the fine pitch of the wires for
chip scale components, and the fine pitch of the wire bonds
for the wires.

15 Another aspect of conventional metal leadframes is
that the leadfingers are configured to form the terminal
contacts as leads. However, it would be desirable for the
leadframe to provide bonding sites for terminal contacts in
the form of bumps, balls or pins in an area array, as is
20 conventional for chip scale components.

The present invention is directed to a semiconductor
component constructed with a metal leadframe designed to
eliminate shorting between the wires and the bus bars on
the leadframe. In addition, the metal leadframe is
25 designed to provided bonding sites for attaching bumps,
balls or pins in an area array, such as a ball grid array.

Summary of the Invention

In accordance with the present invention, an improved
30 semiconductor component, a method for fabricating the
component, and electronic systems incorporating the
component are provided.

The component includes a leadframe, a semiconductor
die back bonded to the leadframe in a chip on board
35 configuration, and wire interconnects bonded to the die and
to the leadframe. The component also includes an array of
terminal contacts attached to the leadframe, and an
encapsulant encapsulating the die, the wire interconnects
and the leadframe.

5 The leadframe includes leadfingers having interconnect bonding sites for the wire interconnects, and terminal bonding sites for the terminal contacts. In addition, the terminal bonding sites can be arranged in an area array such as a grid array, edge array or peripheral array. The
10 leadframe also includes bus bars which physically and electrically connect selected leadfingers to one another. The bus bars are located proximate to inner portions of the leadfingers, and the interconnect bonding sites are located proximate to outer portions of the leadfingers, such that
15 shorting between the bus bars and the wire interconnects is eliminated.

 The fabrication method includes the steps of providing the leadframe, attaching the die to the leadframe, bonding the wire interconnects to the die and to the interconnect
20 bonding sites, forming the encapsulant, and then forming the terminal contacts on the terminal bonding sites.

 The component can be used to construct electronic systems such as modules, computers, camcorders, cameras and cell phones.

25

Brief Description of the Drawings

 Figure 1A is an enlarged schematic plan view of a semiconductor component constructed in accordance with the invention;

30 Figure 1B is an enlarged schematic side elevation view of the component;

 Figure 1C is an enlarged schematic cross sectional view of the component taken along line 1C-1C of Figure 1A;

35 Figure 1D is an enlarged schematic bottom view of the component taken along line 1D-1D of Figure 1C;

 Figure 1E is an enlarged schematic cross sectional view of the component taken along line 1E-1E of Figure 1C;

5 Figure 1F is an enlarged schematic cross sectional view, partially cut away, of the component taken along line 1F-1F of Figure 1C;

10 Figures 2A-2E are enlarged schematic cross sectional views illustrating steps in a method for fabricating the component of Figures 1A-1F;

 Figure 3A is an enlarged schematic plan view of a leadframe strip used in the fabrication method taken along line 3A-3A of Figure 2A;

15 Figure 3B is an enlarged schematic plan view of a semiconductor die used in the fabrication method taken along line 3B-3B of Figure 2B;

 Figure 3C is an enlarged schematic cross sectional view of an interconnect bonding site on the leadframe taken along line 3C-3C of Figure 2B;

20 Figure 3D is an enlarged schematic cross sectional view of a terminal bonding site on the leadframe taken along line 3D-3D of Figure 2B;

25 Figure 4A is a schematic plan view of a module system incorporating one or more components constructed in accordance with the invention;

 Figure 4B is a schematic cross sectional view of the module system taken along line 4B-4B of Figure 4A;

30 Figure 5 is a schematic cross sectional view of a computer system incorporating one or more components constructed in accordance with the invention;

 Figure 6 is a schematic cross sectional view of a camcorder system incorporating one or more components constructed in accordance with the invention;

35 Figure 7 is a schematic cross sectional view of a camera system incorporating one or more components constructed in accordance with the invention; and

 Figure 8 is a schematic cross sectional view of a cellular phone system incorporating one or more components constructed in accordance with the invention.

5 Detailed Description of the Preferred Embodiments

Referring to Figures 1A-1F, a semiconductor component 10 constructed in accordance with the invention is illustrated. As used herein, the term "semiconductor component" refers to an electronic element that includes a semiconductor die. Exemplary semiconductor components include semiconductor packages, semiconductor dice and BGA devices. In the illustrative embodiment the component 10 comprises a chip scale semiconductor package.

The component 10 includes a leadframe 12, a semiconductor die 14 back bonded to the leadframe 12, and wire interconnects 16 wire bonded to the die 14 and to the leadframe 12. The component 10 also includes an array of terminal contacts 18 attached to the leadframe 12, and an encapsulant 20 encapsulating the die 14, the wire interconnects 16 and the leadframe 12.

The die 14 can comprise a conventional semiconductor die having active semiconductor devices constructed in a desired electrical configuration. For example, the die 14 can comprise a high speed digital logic device, such as a dynamic random access memory (DRAM), a static random access memory (SRAM), a flash memory, a microprocessor, a digital signal processor (DSP), or an application specific integrated circuit (ASIC). In addition, the die 14 can comprise a tested die that has been certified as a known good die.

In the illustrative embodiment, the die 14 is generally rectangular shaped with opposed lateral edges and opposed longitudinal edges. However, the die 14 can have any polygonal shape, such as square or triangular, and can also have a circular or oval shape. As shown in Figure 1C, the die 14 is mounted to the leadframe 12 in a chip on board configuration. As used herein, the term "chip on board" means the die 14 has a back side 21 (Figure 1C) bonded to the leadframe 12, and a circuit side 22 (Figure

5 1C) having die contacts 24 (Figure 1C) electrically interconnected to the leadframe 12 using a bonding process such as wire bonding.

As shown in Figure 1F, the die contacts 24 are square pads arranged in two rows proximate to the longitudinal
10 edges of the die 14. However, this arrangement is merely exemplary, and the die contacts 24 can have any desired shape (e.g., round, rectangular) and any selected pattern (e.g., peripheral edge array, center array). In addition, the die contacts 24 can comprise the device bond pads, or
15 alternately redistribution pads, in electrical communication with the integrated circuits contained on the die 14. Further, the die contacts 24 can comprise one or more layers of metal, and preferably include a wire bondable outer layer, such as Al, Au, Cu, or alloys of
20 these metals.

The component 10 also includes adhesive members 26 configured to attach the back side 21 of the die 14 to the leadframe 12. The adhesive members 26 can comprise an electrically insulating tape material, such as a polyimide
25 tape, having an adhesive material on one or both sides (e.g., "KAPTON" tape manufactured by DuPont). The adhesive members 26 can also comprise a curable die attach polymer, such as an epoxy, an acrylic, or a polyimide material. In the illustrative embodiment there are two spaced, generally
30 rectangular shaped adhesive members 26 located proximate to longitudinal peripheral edges of the die 14. However, this arrangement is merely exemplary and other arrangements, such as one or more rows of adhesive dots can be employed.

The leadframe 12 is constructed to allow the die 14 to
35 be mounted to the leadframe 12 in a chip on board configuration substantially as described above. This type of leadframe 12 is sometimes termed a chip on board leadframe. As shown in Figure 1E, the leadframe 12 includes a pattern of leadfingers 28, which form an

5 internal signal transmission system for the component 10.
The leadfingers 28 also include inner tip portions arranged
to provide a die mounting site 42 (Figure 3A) for
supporting for the die 14.

10 In the illustrative embodiment, the leadfingers 28 are
arranged in parallel spaced rows, and there are two
patterns of rows along opposing longitudinal edges of the
leadframe 12. However, in actual practice the leadfingers
28 can be formed in an irregular electronic pattern, similar to metal traces on a printed circuit board. In
15 addition, the leadfingers 28 can comprise a suitable metal
such as an iron-nickel alloy or a copper alloy. Further,
the leadfingers 28 can be fabricated using a conventional
process such as stamping or etching, combined with plating
if required.

20 As also shown in Figure 1E, the leadframe 12 also
includes a pattern of terminal bonding sites 30 on the
leadfingers 28 for the terminal contacts 18, and a pattern
of interconnect bonding sites 32 on the leadfingers 28 for
the wire interconnects 16. The terminal bonding sites 30
25 and the interconnect bonding sites 32 are located on
opposing surfaces of the leadfingers 28 substantially as
shown in Figure 1C. In this regard the interconnect
bonding sites 32 are located on a first surface of the
leadframe 12 and the terminal bonding sites 30 are located
30 on an opposing second surface of the leadframe 12. In this
case the first surface and the second surface are the major
planar surfaces of the leadframe 12. The leadframe 12 also
include bus bars 34, which physically and electrically
connect selected leadfingers 28 to one another. Because
35 the leadfingers 28 include the terminal bonding sites 30,
and the interconnect bonding sites 32, the bus bars 34
electrically connect selected terminal bonding sites 30 and
selected interconnect bonding sites 32 as well.

5 As shown in Figure 1E, the terminal bonding sites 30 are arranged in a selected pattern, such as an area array. The pattern of the terminal bonding sites 30 determines the pattern of the terminal contacts 18. In the illustrative embodiment, there are thirty-two terminal bonding sites 30
10 and thirty-two terminal contacts 18 arranged in a grid array of four rows and eight columns. However, this arrangement is merely exemplary, and the terminal bonding sites 30 and the terminal contacts 18 can be arranged in any desired pattern or area array such as an edge array, a
15 peripheral array or a center array. Also in the illustrative embodiment, the terminal bonding sites 30 are generally circular shaped pads formed integrally with the leadfingers 28 by stamping, etching, plating or other suitable method. However, the terminal bonding sites 30
20 can have any polygonal shape (e.g., square, rectangular). Further, the terminal bonding sites 30 can be formed separate from, but in electrical communication with the leadfingers 28.

Further, the terminal bonding sites 30 can comprise
25 one or more layers of metal, such as an outer metal layer, such as Al, Au, Cu, or alloys of these metals, which facilitates bonding or forming of the terminal contacts 18 on the terminal bonding sites 30. A suitable process such as electrolytic deposition, electroless deposition, or CVD
30 can be used to deposit an outer metal layer on the leadfingers 28 to form the terminal bonding sites 30 out of such a bondable metal.

As shown in Figure 1E, the interconnect bonding sites 32 are located proximate to an outer periphery of the
35 component 10 in a peripheral array, and are separated from the bus bars 34. Stated differently, the interconnect bonding sites 32 are located proximate to outer portions 36 of the leadfingers 28, and the bus bars 34 are located proximate to inner portions 38 of the leadfingers 28. In

5 addition, the leadframe 12 includes a space 40 which separates the patterns of leadfingers 28 and the bus bars 34, on opposing sides of the component 10.

10 The location of the interconnect bonding sites 32 relative to the bus bars 34, permits the wire interconnects 16 to be wire bonded to the die 14 and the leadframe 12 without shorting to the bus bars 34. As shown in Figure 1F, the die 14 substantially covers the bus bars 34, and the wire interconnects 16 extend from the die contacts 24 to the interconnect bonding sites 32 without crossing or
15 touching the bus bars 34.

In the illustrative embodiment, the interconnect bonding sites 32 are generally rectangular shaped pads formed integrally with the leadfingers 28 by stamping, etching, plating or other suitable method. However, the
20 interconnect bonding sites 32 can have any shape, and can be formed separate from, but in electrical communication with, the leadfingers 28. As with the terminal bonding sites 30, the interconnect bonding sites 32 can include an outer metal layer, such as Al, Au, Cu, or alloys of these
25 metals, which facilitates wire bonding of the wire interconnects 16.

As shown in Figure 1C, the terminal contacts 18 are formed on the terminal bonding sites 30. The terminal contacts 18 are also sometimes referred to in the art as
30 outer lead bonds (OLB). In the illustrative embodiment, the terminal contacts 18 comprise metal bumps or balls. However, the terminal contacts 18 can also comprise pins, polymer bumps, spring contacts or any terminal contact or outer lead bond (OLB) known in the art. Also in the
35 illustrative embodiment, there are thirty two terminal contacts 18, arranged in a ball grid array (BGA). However, this arrangement is merely exemplary, and the terminal contacts 18 can be arranged in any area array, such as a fine ball grid array (FBGA), an edge array or a peripheral

5 array, containing any desired number of terminal contacts 18.

Further, in the illustrative embodiment, the terminal contacts 18 have outside diameters on the order of about 300 μm to 350 μm . This makes the terminal contacts 18 much
10 larger in comparison to the other elements of the component 10. However, for illustrative purposes the terminal contacts 18 are shown as being about the same size as other elements of the component 10.

As shown in Figure 1C, the encapsulant 20
15 substantially encapsulates the die 14 and the wire interconnects 16. In addition, the encapsulant 20 is formed on either side of the leadframe 12 and substantially encapsulates the leadfingers 28. The encapsulant 20 also partially encapsulates and electrically insulates the
20 terminal contacts 18 from one another. The encapsulant 20 can comprise a curable polymer material such as an epoxy, a silicone, a polyimide or a transfer molded underfill compound (MUF). In addition, these polymer materials can include fillers, such as silicates, configured to reduce
25 the coefficient of thermal expansion (CTE) and adjust the viscosity of the polymer material. The encapsulant 20 can alternately comprise a photo imageable material such as a resist, which can be patterned using a photolithography process, or a laser imageable material, which can be
30 patterned using a stereographic lithography process.

Referring to Figures 2A-2E, steps in a method for fabricating the component 10 are illustrated. Initially, as shown in Figure 2A, the leadframe 12 can be provided. As shown in Figure 3A, the leadframe 12 can be initially
35 contained on a leadframe strip 44 containing a plurality of leadframes 12. For illustrative purposes, the leadframe strip 44 is illustrated as containing two leadframes 12 for fabricating two components 10 at the same time. However,

5 in actual practice the leadframe strip 44 can include any desired number of leadframes (e.g., 2-12).

As also shown in Figure 3A, the leadframe strip 44 includes parallel spaced side rails 46, 48, which will subsequently be trimmed from the completed components 10
10 (Figure 2E). The side rails 46, 48 include openings 50, 52 which allow the leadframe strip 44 to be handled and indexed by automated leadframe handling machinery, such as tracks, conveyors, and magazines. The leadframe strip 44 also includes connecting segments 54 which separate
15 adjacent leadframes 12, and physically connect the leadfingers 28 on the leadframes 12 to the side rails 46, 48 on the leadframe strip 44. The connecting segments 54 are similar in construction to the bus bars 34, but unlike the bus bars 34, will subsequently be trimmed from the
20 completed components 10 (Figure 2E).

As shown in Figure 2A, each leadframe 12 on the leadframe strip 44 includes opposing patterns of leadfingers 28 separated by the spaces 40. In addition, the leadfingers 28 include the interconnect bonding sites
25 32, and the terminal bonding sites 30 on opposing sides of the leadfingers 28, substantially as previously described. Further, the leadfingers 28 on each leadframe 12 include the die mounting sites 42 for back bonding the die 14 to the leadframe 12 in a chip on board configuration. Still
30 further, the terminal bonding sites 30 are arranged in an area array, such as a grid array, which also determines the pattern of the terminal contacts 18.

Next, as shown in Figure 2B, the semiconductor dice 14 are provided. In addition, a die attach step is performed
35 in which the dice 14 are attached to the leadframe 12. As shown in Figure 3B, each die 14 includes a circuit side 22 wherein the die contacts 24 are located. The die contacts 24 can comprise bond pads or redistribution pads in electrical with the integrated circuits contained on the

5 die 14. In the illustrative embodiment, the die contacts
24 are generally square shaped pads formed along opposing
peripheral edges on the circuit side 22 of the die 14.
However, this arrangement is merely exemplary and other
shapes and patterns for the die contacts 24 can be employed
10 to construct the component 10.

As also shown in Figure 2B, the dice 14 are attached
to the leadframe 12 in a chip on board configuration. The
die attach step can be performed by placing the adhesive
members 26 on the back sides of the dice 14, and then
15 placing the dice 14 on the die mounting sites 42 (Figure
3A) on leadframe 12. Alternately, the adhesive members 26
can be placed on the die mounting sites 42, and then the
dice 14 placed on the adhesive members 26. The die attach
step can be performed using a conventional die attach
20 apparatus configured to apply the adhesive members 26 to
the dice 14 (or to the leadframe 12), and then to press the
dice 14 against the leadframe 12. The adhesive members 26
can comprise a curable polymer material as previously
described, or strips of polymer tape covered with an
25 adhesive material, also as previously described.

Next, as shown in Figure 2C, a bonding step is
performed in which the wire interconnects 16 are bonded to
the die contacts 24 on the dice 14, and to the interconnect
bonding sites 32 on the leadframe 12. In the illustrative
30 embodiment, the wire interconnects 16 comprise metal wires
formed of a material such as Au, Al, or alloys thereof,
such as AlMG or AuSi. With the wire interconnects 16
comprising metal wires, the bonding step can be performed
using a conventional wire bonder apparatus configured to
35 wire bond the wire interconnects 16 to the die contacts 24
and to the interconnect bonding sites 32. As shown in
Figure 3C, the interconnect bonding sites 32 can comprise
pads which include one or more metal layers including a
bondable outer layer, such as Al, Cu, Au or alloys thereof,

5 configured to facilitate the wire bonding process. In addition, the interconnect bonding sites 32 are formed on the first side of the leadframe 12, which is also the side to which the die 14 is attached.

10 Rather than wire interconnects 16 formed by wire bonding, tape automated bonding (TAB) interconnects can be used, and TAB bonding techniques such as thermode bonding, can be employed to bond the TAB interconnects to the die contacts 24 and to the interconnect bonding sites 32. In this case, the TAB interconnects can be contained on a
15 multilayered tape, such as TAB tape, or "ASMAT" manufactured by Nitto Denko of Japan.

As shown in Figure 3A, the wire bonding step is also facilitated by the location of the interconnect bonding sites 32 on the leadframes 12 relative to the location of
20 the bus bars 34 on the leadframes 12. In this regard, the interconnect bonding sites 32 are located proximate to the outer peripheries and opposing outer edges of the leadframes 12. On the other hand, the bus bars 34 are located proximate to the inner portions of the leadframes
25 12 and near the spaces 40 which separate the opposing patterns of leadfingers 28. With the present arrangement, the bonded wire interconnects 16 do not cross the bus bars 34, such that shorting between the wire interconnects 16 and the bus bars 34 cannot occur. Stated differently, the
30 leadframes 12 are configured to allow wire bonding of the wire interconnects 16 to occur without shorting to the bus bars 34. In addition, in the completed component 10, the wire interconnects 16 do not cross the bus bars 34, such that shorting from the wire interconnects 16 to the bus
35 bars 34 again cannot occur.

Next, as shown in Figure 2D, an encapsulating step is performed in which the encapsulants 20 are formed on the leadframe strip 44. The encapsulants 20 function to protect the wire interconnects 16 and associated wire

5 bonds, and to seal the dice 14 on the leadframes 12. As
such, the encapsulants 20 cover and encapsulate the wire
interconnects 16 and the dice 14. In addition, the
encapsulants seal and substantially cover both major
surfaces of the leadframes 12, but do not cover the
10 terminal bonding sites 30 on the leadframes 12. The
encapsulants 20 also form the outer bodies and make up the
bulk of the components 10. Further, each encapsulant 20
has a generally square shape when view from above, and a
thickness that is only slightly greater than the thickness
15 of the die 14 and the leadframe 12 combined. Still
further, each encapsulant 20 has a peripheral outline
matching that of the leadframe 12, and this outline
determines the peripheral outline or footprint of the
component 10. The peripheral outline of each encapsulant
20 16 can be slightly larger than that of the die 14 (e.g.,
1.25 X), such that the component 10 can be considered a
chip scale component.

The encapsulants 20 can comprise a polymer material
such as an epoxy, a silicone, a polyimide or a transfer
25 molded underfill compound (MUF). In addition, these polymer
materials can include fillers such as silicates configured
to reduce the coefficient of thermal expansion (CTE) and
adjust the viscosity of the polymer material. One method
for forming the encapsulants 20 is by deposition in a
viscous state in the manner of a "glob top", using a
30 conventional deposition apparatus, such as a material
dispensing system having a computer controlled nozzle. One
suitable system is manufactured by Asymtek of Carlsbad, CA.
Following deposition, the encapsulants 20 can be cured, and
35 if required shaped or planarized using a grinder or other
suitable apparatus. As shown in Figure 1A, each
encapsulant 20 has orthogonal, generally planar surfaces.
The encapsulants 20 can also be transfer molded using a
transfer molding apparatus.

5 Next, as shown in Figure 2E, a terminal contact forming step is performed in which the terminal contacts 18 are formed on the terminal bonding sites 30 on the leadframes 12. As shown in Figure 3D, the terminal bonding sites 30 can comprise pads formed of a bondable metal such as Al, Cu, Au or alloys thereof, to facilitate forming or bonding of the terminal contacts 18. In addition, the terminal bonding sites 30 are formed on the second opposing side of the leadframe 12, which is opposite to the first side to which the die 14 is attached.

10 The terminal contact forming step can be performed by bonding, or depositing, the terminal contacts 18 on the terminal bonding sites 30. For example, the terminal contacts 18 can comprise metal bumps deposited using a suitable deposition process, such as stenciling and reflow of a solder alloy. The terminal contacts 18 can also be formed by electrolytic deposition, by electroless deposition, or by bonding pre-fabricated balls to the terminal bonding sites 30. Also, rather than being formed of metal, the terminal contacts 18 can comprise a conductive polymer material. Still further, the terminal contacts 18 can comprise metal, or metal plated pins.

15 As also shown in Figure 2E, a singulating step is performed in which the leadframe strip 44 (Figure 3A) is trimmed to remove the siderails 46, 48 (Figure 3A) and the connecting segments 54 (Figure 3A). In addition, the singulating step separates the individual components 10 from the leadframe strip 44, such that each component 10 is a discrete element. The singulating step can be performed using a suitable apparatus such as a saw or a shear.

20 Referring to Figures 4A and 4B, a multi chip module system 56 that includes multiple components 10 is illustrated. The multi chip module system 56 can be configured for performing a specific function such as memory storage. The multi chip module system 56 includes a

5 module substrate 58 having patterns of electrodes 64
(Figure 4B) configured for flip chip mounting the
components 10 to the module substrate 58. The terminal
contacts 18 on the components 10 can be bonded to the
electrodes 64 on the module substrate 58 using a suitable
10 bonding process, such as solder reflow, thermode bonding or
conductive polymer bonding. The electrodes 64 are in
electrical communication with conductors 60 formed on the
module substrate 58 in a required circuit pattern. In
addition, the conductors 60 are in electrical communication
15 with an edge connector 62 which provides connection points
from the outside to the multi chip module system 56.

Referring to Figure 5, a computer system 66 includes
one or more components 10, which can be mounted to the
computer system 66 in a suitable manner. In addition, the
20 components 10 can be configured to perform a desired
function in the computer system 66 such as memory, storage
or micro processing.

Referring to Figure 6, a digital camcorder system 68
includes one or more components 10, which can be mounted in
a suitable manner, and configured to perform a desired
25 circuit function in the camcorder system 68.

Referring to Figure 7, a camera system 70 includes one
or more components 10, which can be mounted in a suitable
manner, and configured to perform a desired circuit
30 function in the camera system 70.

Referring to Figure 8, a cellular phone system 72
includes one or more components 10, which can be mounted to
in a suitable manner, and configured to perform a desired
circuit function in the cellular phone system 72.

35 Thus the invention provides an improved chip scale
semiconductor component, a method for fabricating the
component, and a system incorporating the component. While
the invention has been described with reference to certain
preferred embodiments, as will be apparent to those skilled

5 in the art, certain changes and modifications can be made without departing from the scope of the invention as defined by the following claims.